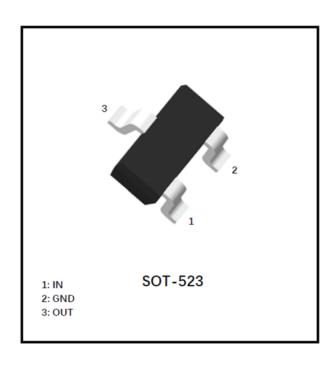




NPN Digital Transistors (Built-in Resistors)



Features

- Moisture sensitivity level 1
- Halogen free and RoHS compliant
- Surface mount package ideally suited for auto matic insertion

Application

- Signal amplification
- Switching circuit

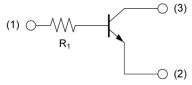
Mechanical data

• Package: SOT-523

• Terminals: Tin plated leads, solderable per

J-STD-002 and JESD22-B102

■Equivalent circuit



- (1) BASE
- (2) EMITTER
- (3) COLLECTOR

■ Maximum Ratings (Ta=25°C Unless otherwise specified)

ltem	Symbol	Unit	Conditions	Value
Device Marking Code				N16
Collector-Base Voltage	V _{CBO}	V		50
Collector-Emitter Voltage	V _{CEO}	V		50
Emitter-Base Voltage	V _{EBO}	V		5
Output Current	Io	mA		100
Power Dissipation	P _D	mW		150
Junction Temperature	TJ	°C		-55 to +150
Storage Temperature	T _{STG}	°C		-55 to +150

1/5



■ Electrical Characteristics (T_a=25°C Unless otherwise specified)

Item	Symbol	Unit	Conditions	Min	Тур	Max
Collector-Base Breakdown Voltage	V _{CBO}	V	I _C =1mA	50		
Collector-Emitter Breakdown Voltage	V _{CEO}	V	I _C =1mA	50		
Emitter-Base Breakdown Voltage	V _{EBO}	V	I _E =50uA	5		
Collector Cut-off Current	I _{CBO}	uA	V _{CB} =50V			0.5
Emitter Cut-off Current	I _{EBO}	uA	V _{EB} =4V			0.5
DC Current Gain	h _{FE}		V _{CE} =5V, I _C =1mA	100		600
Input Resistance	R ₁	kΩ		15.4	22	28.6
Collector-Emitter Saturation Voltage	V _{CE(sat)}	V	I _C =5mA,I _B =0.5mA			0.3
Transition Frequency	f _T	MHz	V _{CE} =10V,I _E =-5mA,f=100MHz		250	

■ Thermal Characteristics

Parameter	Symbol	Unit	Value
Thermal resistance, junction-to-ambient	RθJ-A ⁽¹⁾	°C/W	833
Thermal resistance, junction-to-case	RθJ-C ⁽¹⁾	°C/W	666

Note:

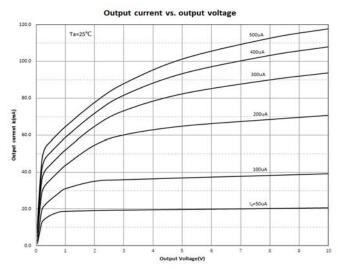
(1) Thermal resistance from junction to ambient and from junction to case mounted on P.C.B. with 25.4mm*25.4mm copper pad areas

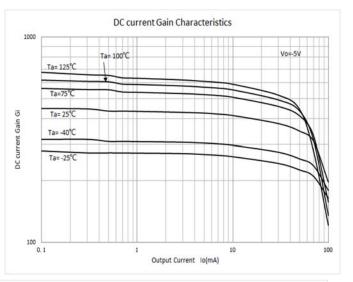
■Ordering Information

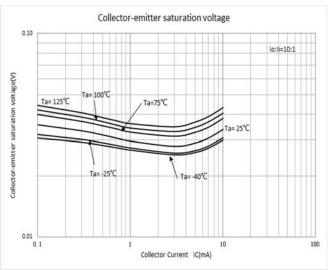
Preferred P/N	Packing code	Unit weight(g)	Minimum package(pcs)	Inner box quantity(pcs)	Outer carton quantity(pcs)	Delivery mode
DTC124TE	F2	Approximate 0.0027	3000	30000	120000	7" reel

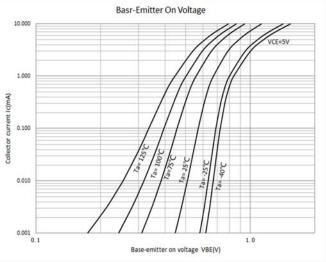


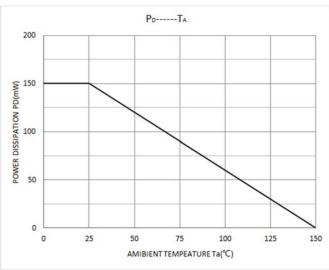
■Characteristics(Typical)





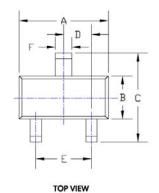


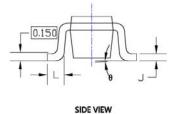






■ Outline Dimensions

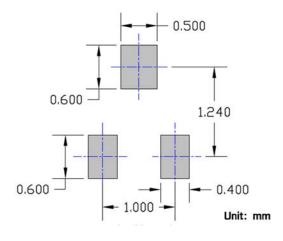




G SIDE VIEW

DIMENSIONS						
SYMBUI	INC	HES	Millimeter			
2 I M R II L	MIN.	MAX.	MIN.	MAX.		
Α	0.059	0.067	1.500	1.700		
В	0.030	0.033	0.750	0.850		
С	0.057	0.069	1.450	1.750		
D	0.02	0TYP	0.500TYP			
E	0.035	0.043	0.900	1.100		
F	0.010	0.018	0.250	0.450		
G	0.000	0.004	0.000	0.100		
Н	0.024	0.031	0.600	0.800		
J	0.004	0.008	0.100	0.200		
K	0.006	0.014	0.150	0.350		
L	0.010	0.018	0.260	0.460		
θ	0°	8°	0°	8°		

■ Suggested Pad Layout





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